## NSN 5961-01-469-0533

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View Online at https://aerobasegroup.com/nsn/5961-01-469-0533 **Inclosure Material:** Metal **Overall Length:** 0.340 inches **Overall Diameter:** 0.620 inches **End Application:** 662-15-064-3505 test set electronics systems x925-501 **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 70.0 breakdown voltage, collector-to-base, emitter open and 5.0 breakdown voltage, emitter-to-base, collector open and 65.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 6.00 amperes source cutoff current and 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 40.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Same as 2n5955 but with different quality level; junction pattern arrangement: pnp **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Mil-std (military Standard): Mil-prf-19500 spec.

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